

ISL9K3060G3

30A, 600V Stealth™ Dual Diode

General Description

The ISL9K3060G3 is a StealthTM dual diode optimized for low loss performance in high frequency hard switched applications. The StealthTM family exhibits low reverse recovery current ($I_{RM(REC)}$) and exceptionally soft recovery under typical operating conditions.

This device is intended for use as a free wheeling or boost diode in power supplies and other power switching applications. The low $I_{RM(REC)}$ and short t_a phase reduce loss in switching transistors. The soft recovery minimizes ringing, expanding the range of conditions under which the diode may be operated without the use of additional snubber circuitry. Consider using the Stealth $^{\rm TM}$ diode with an SMPS IGBT to provide the most efficient and highest power density design at lower cost.

Formerly developmental type TA49411.

Features

•	Soft Recovery $t_b/t_a > 1.2$
•	Fast Recovery t_{rr} < 35ns
•	Operating Temperature 175°C
•	Reverse Voltage

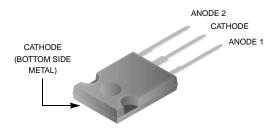
Avalanche Energy Rated

Applications

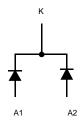
- Switch Mode Power Supplies
- · Hard Switched PFC Boost Diode
- · UPS Free Wheeling Diode
- · Motor Drive FWD
- SMPS FWD
- · Snubber Diode

Package

JEDEC STYLE TO-247



Symbol



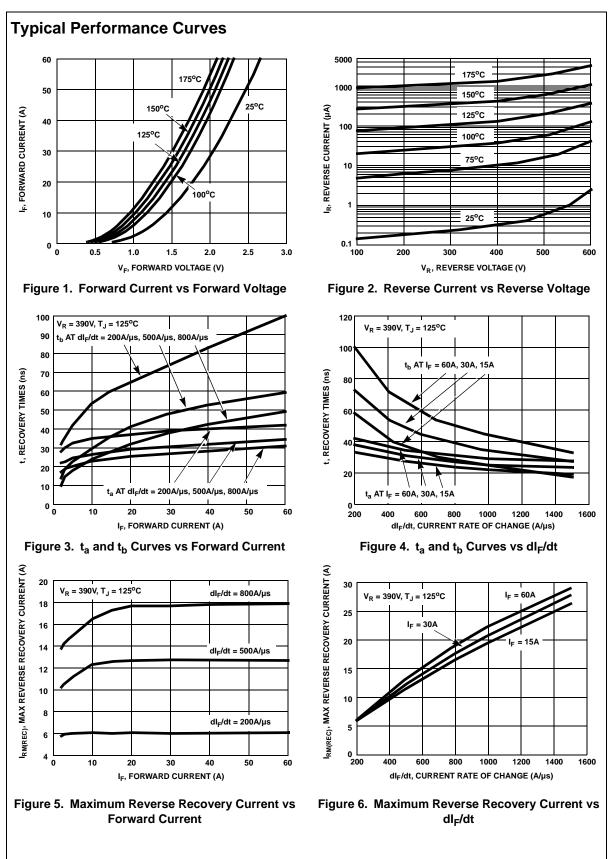
Device Maximum Ratings (per leg) T_C = 25°C unless otherwise noted

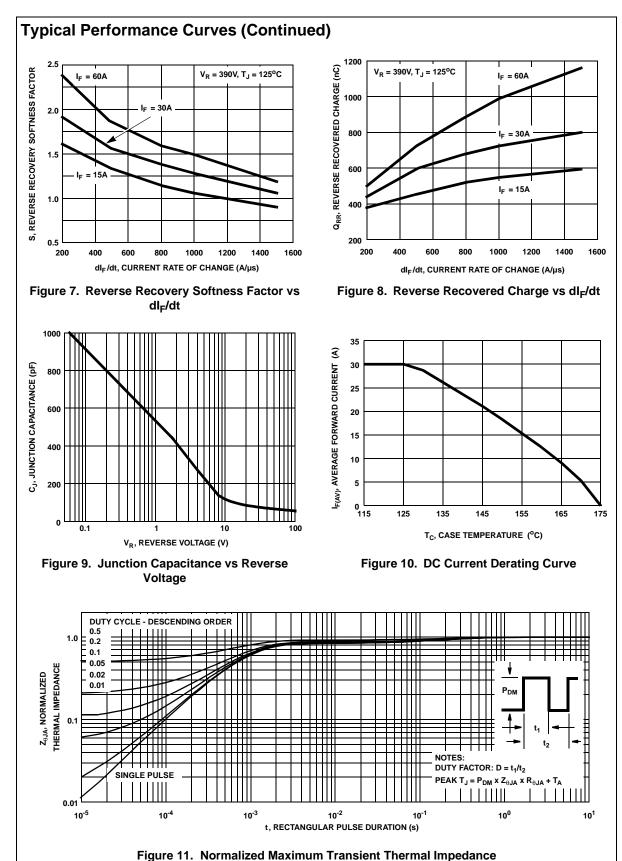
Symbol	Parameter	Ratings	Units
V _{RRM}	Repetitive Peak Reverse Voltage	600	V
V _{RWM}	Working Peak Reverse Voltage	600	V
V _R	DC Blocking Voltage	600	V
I _{F(AV)}	Average Rectified Forward Current (T _C = 125°C) Total Device Current (Both Legs)	30 60	A A
I _{FRM}	Repetitive Peak Surge Current (20kHz Square Wave)	70	Α
I _{FSM}	Nonrepetitive Peak Surge Current (Halfwave 1 Phase 60Hz)	325	Α
P _D	Power Dissipation	200	W
E _{AVL}	Avalanche Energy (1A, 40mH)	20	mJ
T _J , T _{STG}	Operating and Storage Temperature Range	-55 to 175	°C
TL	Maximum Temperature for Soldering		
T _{PKG}	Leads at 0.063in (1.6mm) from Case for 10s Package Body for 10s, See Techbrief TB334	300 260	°C

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

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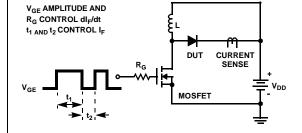
$V_{R} = 600V$ $V_{R} = 600V$ $V_{R} = 10V, I_{I}$ $V_{R} = 10V, I_{I}$ $V_{R} = 30A, dI$ $V_{R} = 390V, dI$	$V_{R} = 100 \text{A}/\mu \text{s}, V_{R} = 30 \text{A}/\mu \text{s}, V_{$	Min - - -	Typ - -	100 1.0 2.4 2.1 - 35 45 -	μΑ mA V V V PF
$V_{R} = 600V$ $V_{R} = 600V$ $V_{R} = 10V, I_{I}$ $V_{R} = 10V, I_{I}$ $V_{R} = 30A, dI$ $V_{R} = 390V, dI$	Test Conditions $T_{C} = 25^{\circ}C$ $T_{C} = 125^{\circ}C$	Min - -	- - 1.7 120 27 36 36 2.9	100 1.0 2.4 2.1 - 35 45 -	μA mA
$V_{R} = 600V$ $V_{R} = 600V$ $V_{R} = 10V, I_{I}$ $V_{R} = 10V, I_{I}$ $V_{R} = 30A, dI$ $V_{R} = 390V, dI$	Test Conditions $T_{C} = 25^{\circ}C$ $T_{C} = 125^{\circ}C$	Min - -	- - 1.7 120 27 36 36 2.9	100 1.0 2.4 2.1 - 35 45 -	μA mA
$V_{R} = 600V$ $V_{R} = 10V, I_{I}$ $V_{R} = 10V, I_{I}$ $V_{R} = 10V, I_{I}$ $V_{R} = 30A, dI$ $V_{R} = 30A, dI$ $V_{R} = 390V, dI_{F} = 30A, dI_{F}/dt = 20C$ $V_{R} = 390V, dI_{F} = 390V, dI_{F}/dt = 20C$ $V_{R} = 390V, dI_{F}/dt = 20C$ $V_{R} = 390V, dI_{F}/dt = 20C$ $V_{R} = 390V, dI_{F}/dt = 20C$	$T_{C} = 25^{\circ}C$ $T_{C} = 125^{\circ}C$		- - 1.7 120 27 36 36 2.9	100 1.0 2.4 2.1 - 35 45 -	μA mA
$\begin{aligned} & I_F = 30A \\ & V_R = 10V, I_1 \\ & I_F = 1A, dI_F \\ & I_F = 30A, dI_F \\ & I_F = 30A, dI_F/dt = 200, dI_F/dt = 20$	$T_{C} = 125^{\circ}C$ $T_{C} = 25^{\circ}C$ $T_{C} = 125^{\circ}C$		2.1 1.7 120 27 36 36 2.9	2.4 2.1 - 35 45	m/A V V PF
$\begin{aligned} & I_F = 30A \\ & V_R = 10V, I_1 \\ & I_F = 1A, dI_F \\ & I_F = 30A, dI_F \\ & I_F = 30A, dI_F/dt = 200, dI_F/dt = 20$	$T_{C} = 125^{\circ}C$ $T_{C} = 25^{\circ}C$ $T_{C} = 125^{\circ}C$		2.1 1.7 120 27 36 36 2.9	2.4 2.1 - 35 45	m/A V V PF
$\begin{aligned} V_R &= 10 \text{V}, I_I \\ I_F &= 1 \text{A}, dI_F \\ I_F &= 30 \text{A}, dI_F \\ I_F &= 30 \text{A}, dI_F \\ V_R &= 390 \text{V}, \\ I_F &= 30 \text{A}, \\ dI_F / dt &= 200 \text{V}, \\ I_F &= 300 \text{V}, \\ I_F &= 300 \text{V}, \\ I_F &= 300 \text{V}, \end{aligned}$	$T_{C} = 125^{\circ}C$ $T_{C} = 25^{\circ}C$ $T_{C} = 125^{\circ}C$	30V - - 30V -	1.7 120 27 36 36 2.9	2.4 2.1 - 35 45 -	V V PF
$\begin{aligned} V_R &= 10 \text{V}, I_I \\ I_F &= 1 \text{A}, dI_F \\ I_F &= 30 \text{A}, dI_F \\ I_F &= 30 \text{A}, dI_F \\ V_R &= 390 \text{V}, \\ I_F &= 30 \text{A}, \\ dI_F / dt &= 200 \text{V}, \\ I_F &= 300 \text{V}, \\ I_F &= 300 \text{V}, \\ I_F &= 300 \text{V}, \end{aligned}$	$T_C = 125^{\circ}C$ $F = 0A$ $T_C = 100A/\mu s, V_R = 30$ $T_C = 100A/\mu s, V_R = 30$ $T_C = 25^{\circ}C$	30V - - 30V -	1.7 120 27 36 36 2.9	2.1 - 35 45 -	PF ns
$\begin{aligned} V_R &= 10 \text{V}, I_I \\ I_F &= 1 \text{A}, dI_F \\ I_F &= 30 \text{A}, dI_F \\ I_F &= 30 \text{A}, dI_F \\ V_R &= 390 \text{V}, \\ I_F &= 30 \text{A}, \\ dI_F / dt &= 200 \text{V}, \\ I_F &= 300 \text{V}, \\ I_F &= 300 \text{V}, \\ I_F &= 300 \text{V}, \end{aligned}$	$T_C = 125^{\circ}C$ $F = 0A$ $T_C = 100A/\mu s, V_R = 30$ $T_C = 100A/\mu s, V_R = 30$ $T_C = 25^{\circ}C$	30V - - 30V -	1.7 120 27 36 36 2.9	2.1 - 35 45 -	V pF
$\begin{array}{c} I_{F} = 1\text{A, dI}_{F} \\ I_{F} = 30\text{A, dI} \\ I_{F} = 30\text{A,} \\ \text{rrent} \\ V_{R} = 390\text{V,} \\ I_{F} = 30\text{A,} \\ \text{dI}_{F}/\text{dt} = 20\text{C} \\ V_{R} = 390\text{V,} \\ \end{array}$	$T_C = 125^{\circ}C$ $F = 0A$ $T_C = 100A/\mu s, V_R = 30$ $T_C = 100A/\mu s, V_R = 30$ $T_C = 25^{\circ}C$	30V - 30V -	27 36 36 2.9	- 35 45 -	pF ns
$\begin{array}{c} I_{F} = 1\text{A, dI}_{F} \\ I_{F} = 30\text{A, dI} \\ I_{F} = 30\text{A,} \\ \text{rrent} \\ V_{R} = 390\text{V,} \\ I_{F} = 30\text{A,} \\ \text{dI}_{F}/\text{dt} = 20\text{C} \\ V_{R} = 390\text{V,} \\ \end{array}$	$V_{R} = 100 \text{A}/\mu \text{s}, V_{R} = 30 \text{A}/\mu \text{s}, V_{$	30V - : 30V -	27 36 36 2.9	35 45 -	ns ns
$\begin{array}{c} I_{F} = 1\text{A, dI}_{F} \\ I_{F} = 30\text{A, dI} \\ I_{F} = 30\text{A,} \\ \text{rrent} \\ V_{R} = 390\text{V,} \\ I_{F} = 30\text{A,} \\ \text{dI}_{F}/\text{dt} = 20\text{C} \\ V_{R} = 390\text{V,} \\ \end{array}$	$V_{R} = 100 \text{A}/\mu \text{s}, V_{R} = 30 \text{A}/\mu \text{s}, V_{$	30V - : 30V -	27 36 36 2.9	35 45 -	ns ns
$\begin{array}{c} I_{F} = 1\text{A, dI}_{F} \\ I_{F} = 30\text{A, dI} \\ I_{F} = 30\text{A,} \\ \text{rrent} \\ V_{R} = 390\text{V,} \\ I_{F} = 30\text{A,} \\ \text{dI}_{F}/\text{dt} = 20\text{C} \\ V_{R} = 390\text{V,} \\ \end{array}$	$V_{R} = 100 \text{A}/\mu \text{s}, V_{R} = 30 \text{A}/\mu \text{s}, V_{$	30V - : 30V -	27 36 36 2.9	35 45 -	ns ns
$ I_F = 30A, dI I_F = 30A, dI_F = 30A, dI_F = 200, dI_F = 390V, dI_F = 30A, dI_F = 30A, dI_F = 390V, dI_$	$I_F/dt = 100A/\mu s$, $V_R = 0A/\mu s$, $T_C = 25^{\circ}C$	30V -	36 36 2.9	45 -	ns
$ I_F = 30A, dI I_F = 30A, dI_F = 30A, dI_F = 200, dI_F = 390V, dI_F = 30A, dI_F = 30A, dI_F = 390V, dI_$	$I_F/dt = 100A/\mu s$, $V_R = 0A/\mu s$, $T_C = 25^{\circ}C$	30V -	36 36 2.9	45 -	ns
rrent $I_F = 30A$, $dI_F/dt = 200$, $V_R = 390V$, $I_F = 30A$, $dI_F/dt = 200$, $V_R = 390V$, $V_R = 390V$,	DA/μs, T _C = 25°C	-	36 2.9	-	
rrent $dI_F/dt = 200$ $V_R = 390V$, $I_F = 30A$, $dI_F/dt = 200$ $V_R = 390V$,	T _C = 25°C	-	2.9		ne
$V_{R} = 390V,$ $I_{F} = 30A,$ $dI_{F}/dt = 200,$ $V_{R} = 390V,$	T _C = 25°C	-		-	113
$I_F = 30A,$ $dI_F/dt = 200$ $V_R = 390V,$	-	-			Α
$dI_F/dt = 200$ $V_R = 390V,$	OA/us,		55	-	nC
$V_R = 390V$	DA/μs,	-	110	-	ns
	$dI_F/dt = 200A/\mu s,$ $V_R = 390V,$ $-T_C = 125^{\circ}C$ $-T_F = 30A,$		1.9	-	
			6	-	Α
1C = 125 C			450	-	nC
I _F = 30A,			60	-	ns
ess Factor (t_b/t_a) $dI_F/dt = 1000A/\mu s$,			1.25	-	
rrent $V_R = 390V$,	TV _R = 390V, -T _C = 125°C		21	-	Α
1 _C = 125°C			730	-	nC
			800	-	Α/μ
•		<u>'</u>	·I		
Case		<u> </u>	l <u>.</u>	1.0	°C/\
					°C/\
(T _C = 125°C	T _C = 125°C -	$T_{C} = 125^{\circ}C$ $T_{C} = 125$	T _C = 125°C





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Test Circuit and Waveforms



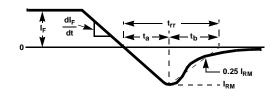
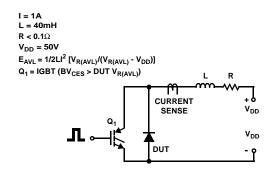


Figure 12. t_{rr} Test Circuit

Figure 13. t_{rr} Waveforms and Definitions



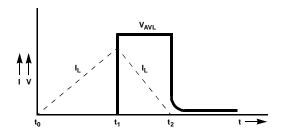


Figure 14. Avalanche Energy Test Circuit

Figure 15. Avalanche Current and Voltage Waveforms

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